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May 2016

FGA40T65UQDF

650 V, 40 A Field Stop Trench IGBT

Features

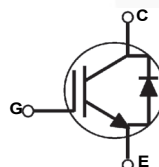
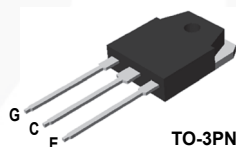
- Maximum Junction Temperature: $T_J = 175^\circ\text{C}$
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.33\text{ V (Typ.) @ } I_C = 40\text{ A}$
- 100% of the Parts tested for $I_{LM}(1)$
- High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- RoHS Compliant

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 4th generation IGBTs offer superior conduction and switching performance and easy parallel operation. This device is well suited for the resonant or soft switching application such as induction heating and MWO.

Applications

- Induction Heating, MWO



Absolute Maximum Ratings

Symbol	Description	FGA40T65UQDF	Unit
V_{CES}	Collector to Emitter Voltage	650	V
V_{GES}	Gate to Emitter Voltage	± 20	V
	Transient Gate to Emitter Voltage	± 30	V
I_C	Collector Current @ $T_C = 25^\circ\text{C}$	80	A
	Collector Current @ $T_C = 100^\circ\text{C}$	40	A
$I_{LM}(1)$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	120	A
$I_{CM}(2)$	Pulsed Collector Current	120	A
I_F	Diode Forward Current @ $T_C = 25^\circ\text{C}$	40	A
	Diode Forward Current @ $T_C = 100^\circ\text{C}$	20	A
I_{FM}	Pulsed Diode Maximum Forward Current	60	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	231	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	115	W
T_J	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
T_L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Notes:

1. $V_{CC} = 400\text{ V}$, $V_{GE} = 15\text{ V}$, $I_C = 120\text{ A}$, $R_G = 20\ \Omega$, Inductive Load
2. Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	FGA40T65UQDF	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case, Max.	0.65	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case, Max.	1.75	$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	40	$^{\circ}\text{C}/\text{W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Qty per Tube
FGA40T65UQDF	FGA40T65UQDF	TO-3PN	-	-	30

Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	650	-	-	V
ΔBV _{CES} / ΔT _J	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	-	0.52	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0 V	-	-	± 400	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 40 mA, V _{CE} = V _{GE}	2.5	4.0	5.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 40 A, V _{GE} = 15 V	-	1.33	1.67	V
		I _C = 40 A, V _{GE} = 15 V, T _C = 175°C	-	1.5	-	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	-	7309	-	pF
C _{oes}	Output Capacitance		-	58	-	pF
C _{res}	Reverse Transfer Capacitance		-	30	-	pF
Switching Characteristics						
T _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 40 A, R _G = 6 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25°C	-	32	-	ns
T _r	Rise Time		-	18	-	ns
T _{d(off)}	Turn-Off Delay Time		-	271	-	ns
T _f	Fall Time		-	11	-	ns
E _{on}	Turn-On Switching Loss		-	989	-	μJ
E _{off}	Turn-Off Switching Loss		-	310	-	μJ
E _{ts}	Total Switching Loss		-	1299	-	μJ
T _{d(on)}	Turn-On Delay Time	V _{CC} = 400 V, I _C = 40 A, R _G = 6 Ω, V _{GE} = 15 V, Inductive Load, T _C = 175°C	-	30	-	ns
T _r	Rise Time		-	22	-	ns
T _{d(off)}	Turn-Off Delay Time		-	298	-	ns
T _f	Fall Time		-	16	-	ns
E _{on}	Turn-On Switching Loss		-	1400	-	μJ
E _{off}	Turn-Off Switching Loss		-	553	-	μJ
E _{ts}	Total Switching Loss		-	1953	-	μJ

Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Q_g	Total Gate Charge	$V_{CE} = 400\text{ V}$, $I_C = 40\text{ A}$, $V_{GE} = 15\text{ V}$	-	306	-	nC
Q_{ge}	Gate to Emitter Charge		-	30	-	nC
Q_{gc}	Gate to Collector Charge		-	77	-	nC

Electrical Characteristics of the Diode $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
V _{FM}	Diode Forward Voltage	I _F = 20 A	T _C = 25°C	-	1.5	1.95	V
			T _C = 175°C	-	1.39	-	
E _{rec}	Reverse Recovery Energy	I _F = 20 A, dI _F /dt = 200 A/μs	T _C = 175°C	-	115	-	μJ
T _{rr}	Diode Reverse Recovery Time		T _C = 25°C	-	89	-	ns
			T _C = 175°C	-	251	-	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	-	289	-	nC
			T _C = 175°C	-	1502	-	

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

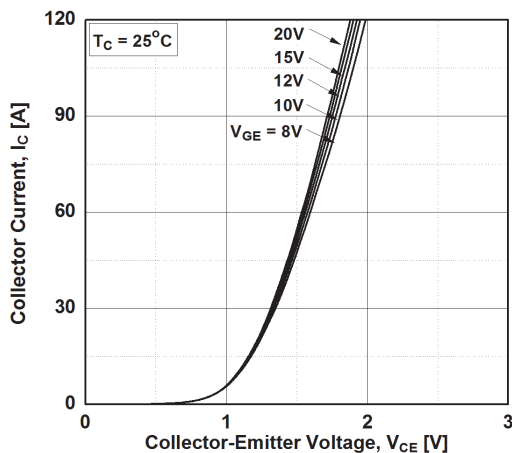


Figure 2. Typical Output Characteristics

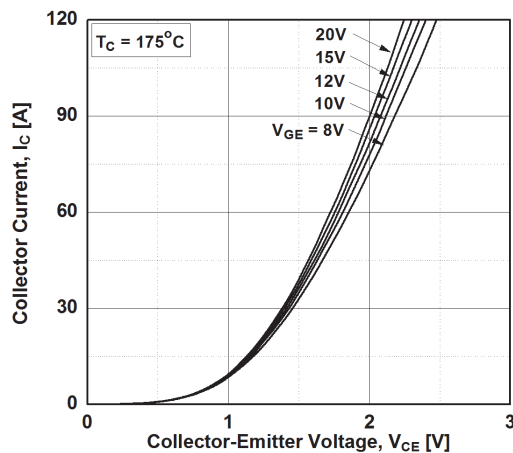


Figure 3. Typical Saturation Voltage Characteristics

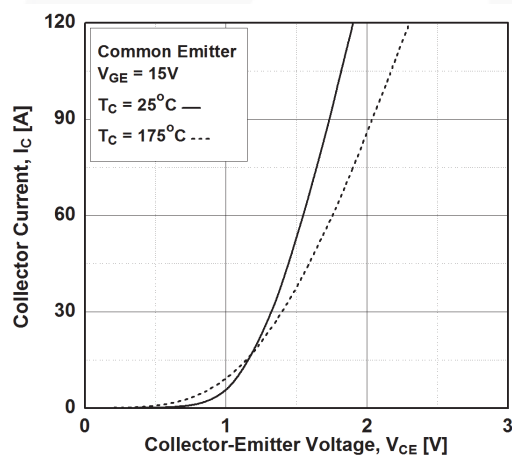


Figure 4. Saturation Voltage vs. Case Temperature at Variant Current Level

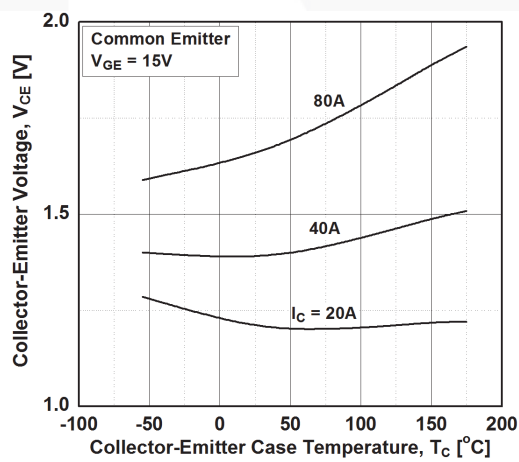


Figure 5. Saturation Voltage vs. V_{GE}

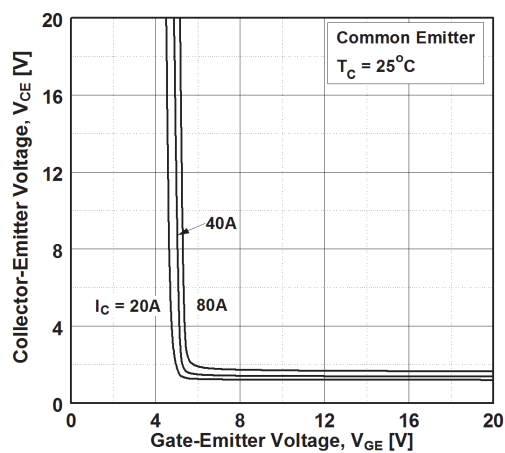
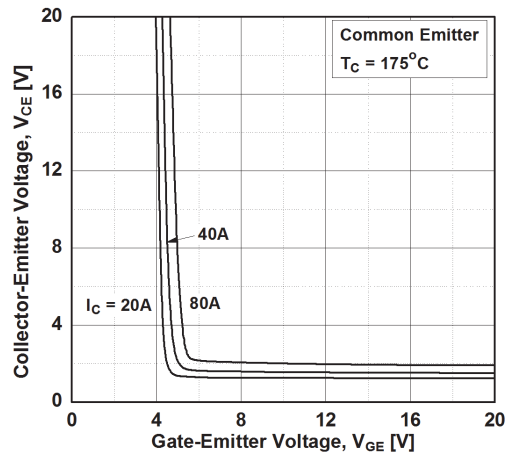


Figure 6. Saturation Voltage vs. V_{GE}



Typical Performance Characteristics

Figure 7. Capacitance Characteristics

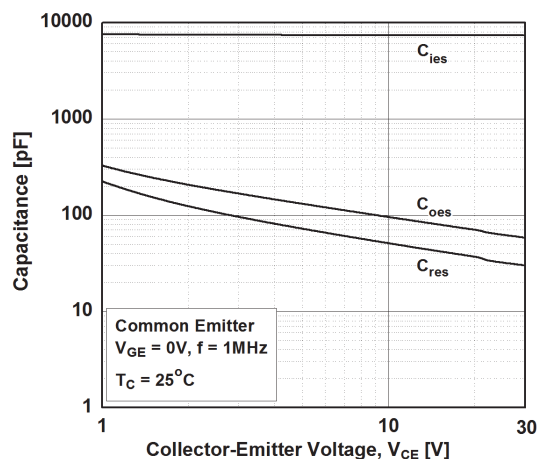


Figure 8. Gate charge Characteristics

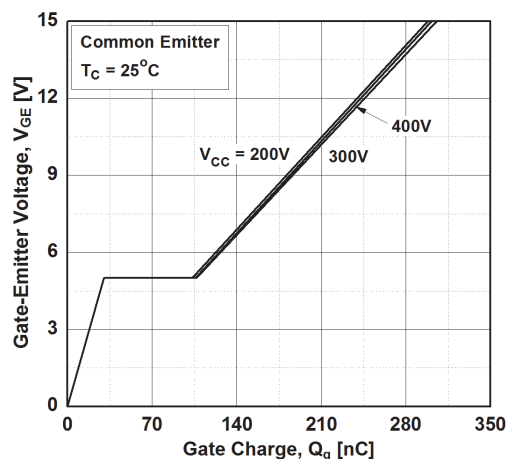


Figure 9. Turn-on Characteristics vs. Gate Resistance

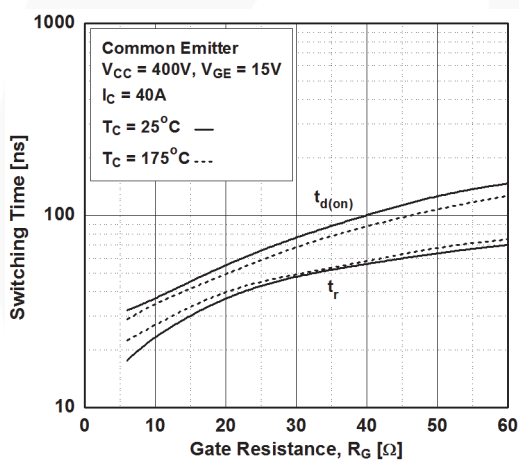


Figure 10. Turn-off Characteristics vs. Gate Resistance

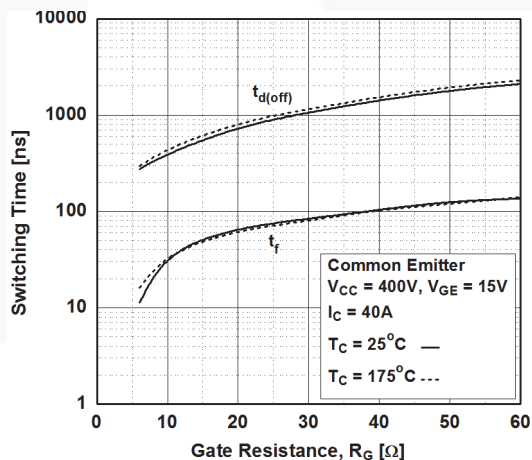


Figure 11. Switching Loss vs. Gate Resistance

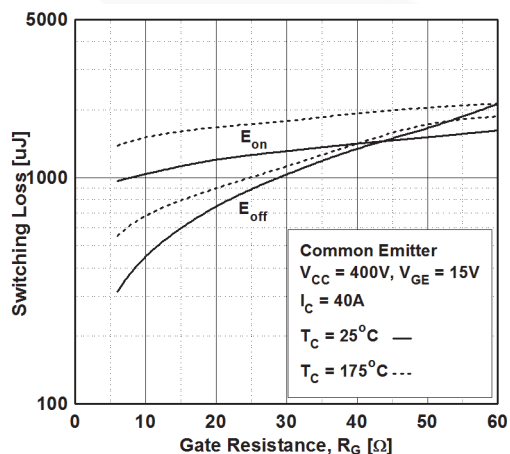
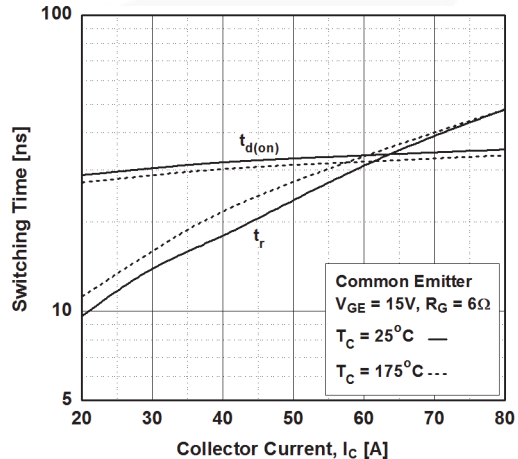


Figure 12. Turn-on Characteristics vs. Collector Current



Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

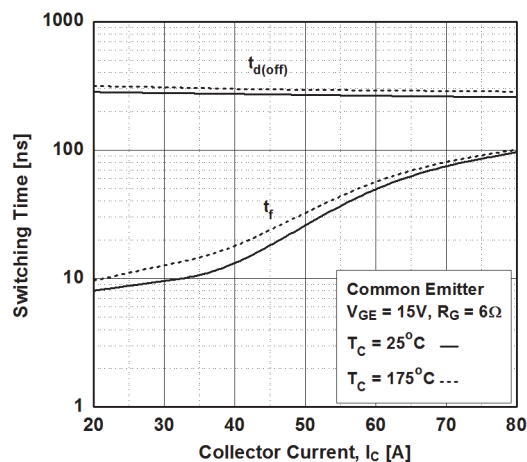


Figure 14. Switching Loss vs. Collector Current

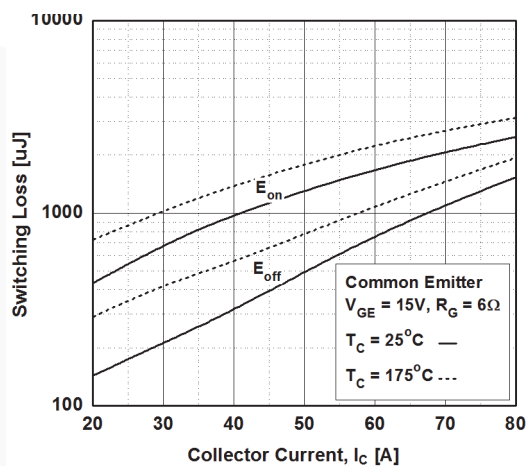


Figure 15. Load Current Vs. Frequency

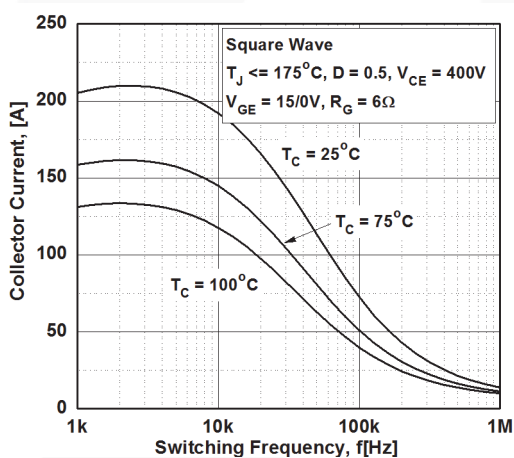


Figure 16. SOA Characteristics

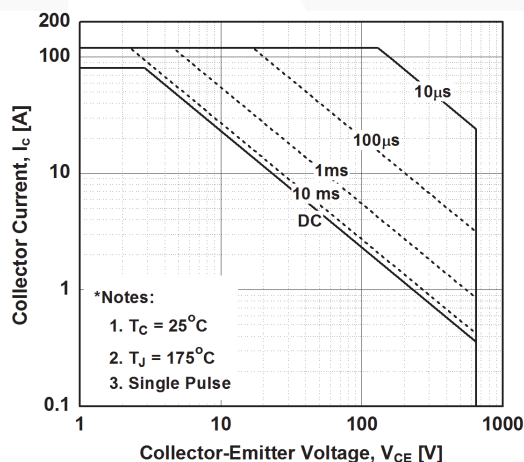


Figure 17. Forward Characteristics

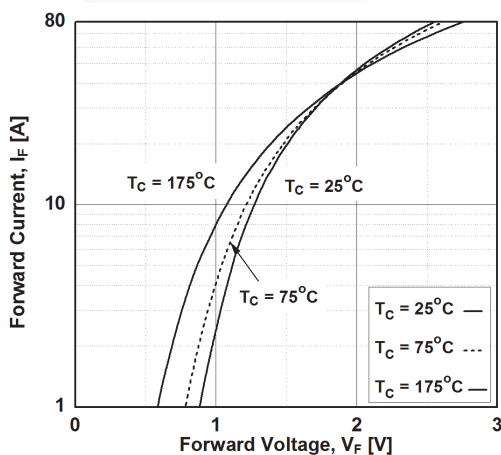
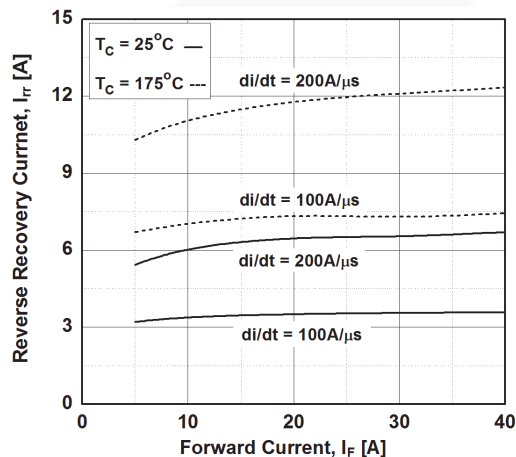


Figure 18. Reverse Recovery Current



Typical Performance Characteristics

Figure 19. Reverse Recovery Time

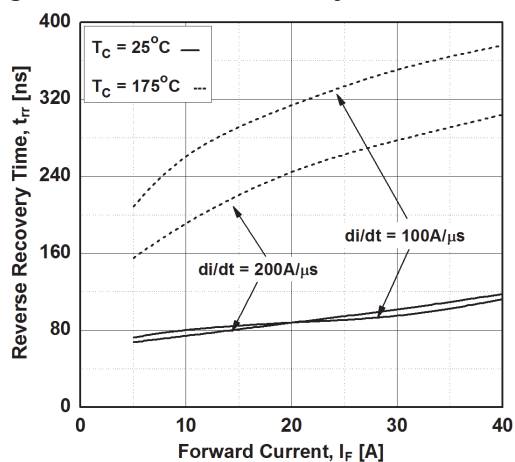


Figure 20. Stored Charge

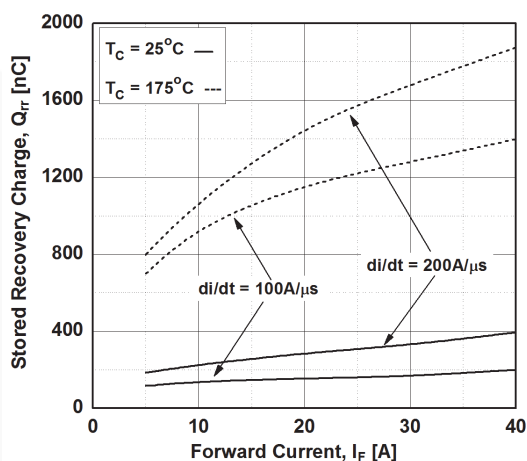


Figure 21. Transient Thermal Impedance of IGBT

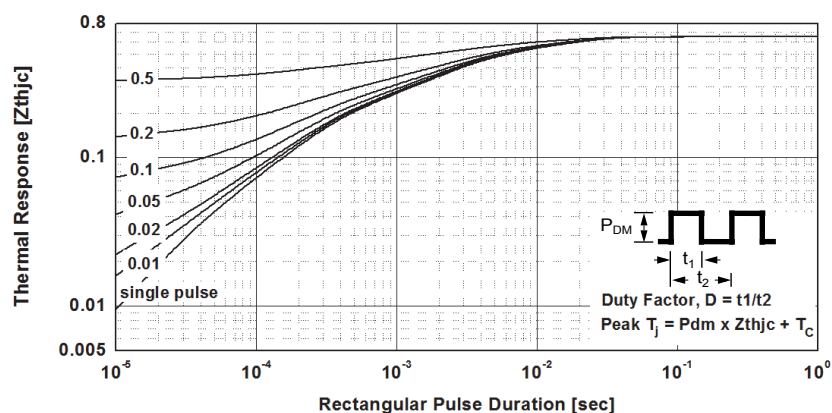
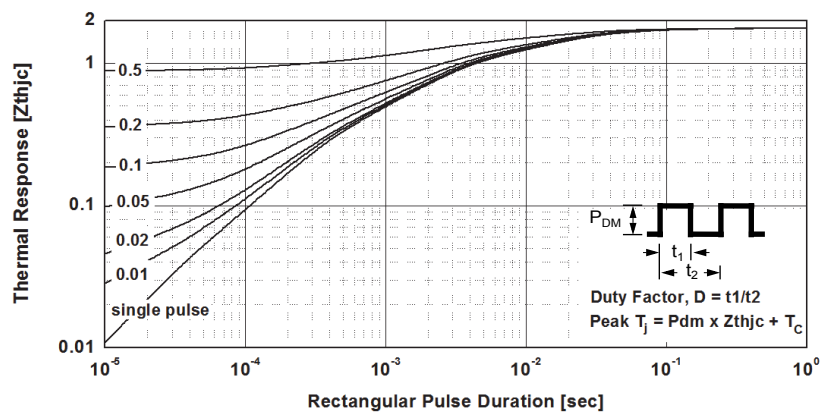


Figure 22. Transient Thermal Impedance of Diode



Mechanical Dimensions

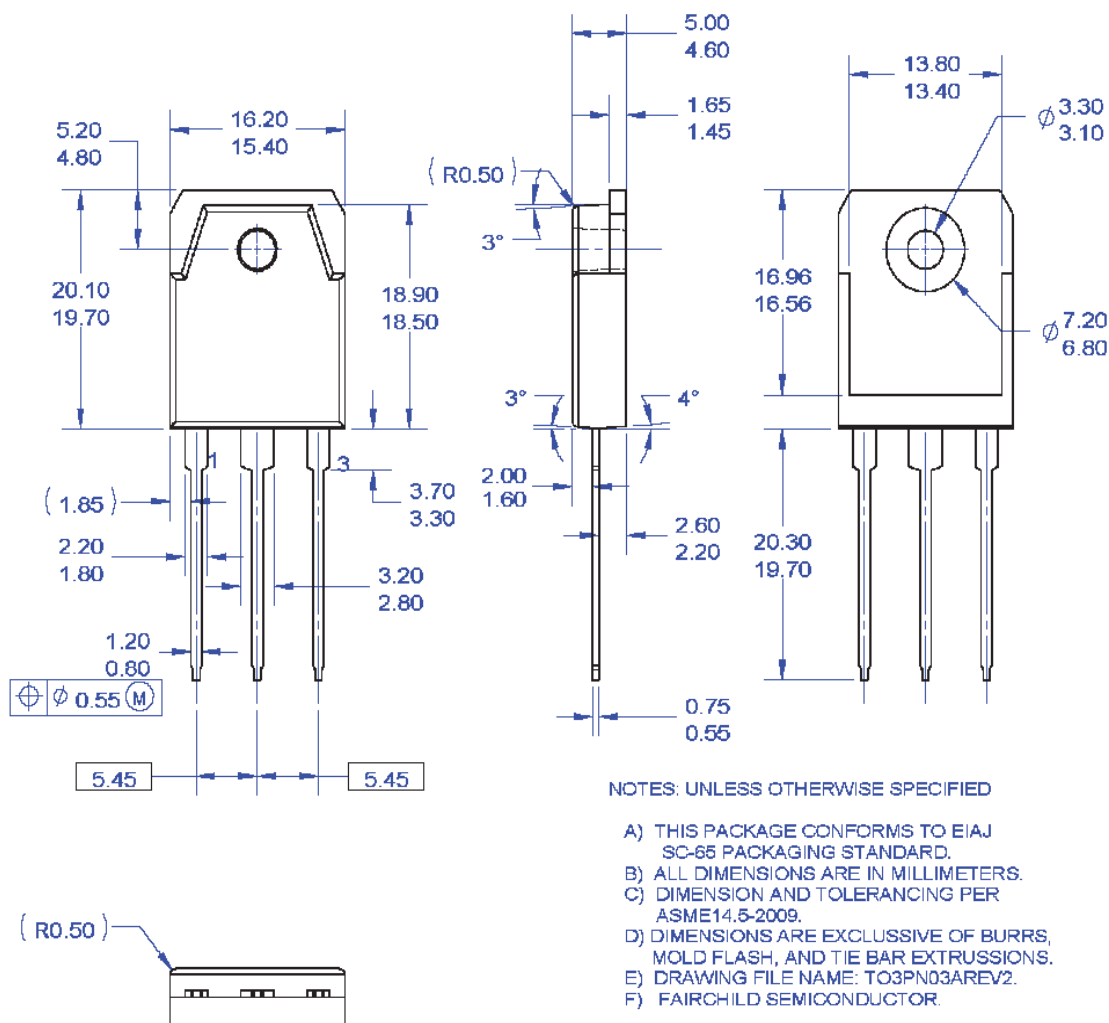


Figure 23. TO3PN, 3-Lead, Plastic, EIAJ SC-65

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